



THYRISTOR MODULE

100A / 1600V

PGH10016AM

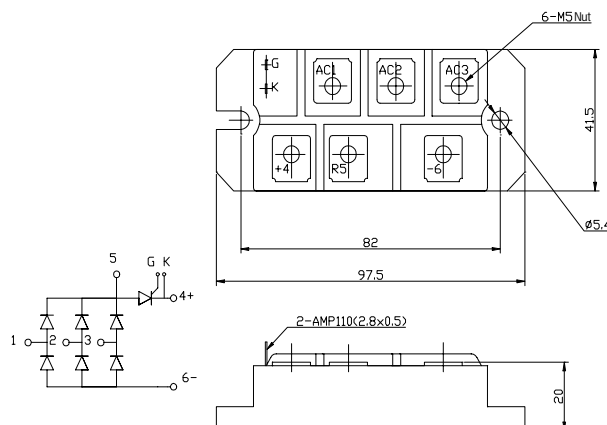
OUTLINE DRAWING

FEATURES

- * Isolated Base
- * 3 Phase Converter with Rush-Current Controllable Thyristor
- * High Surge Capability
- * UL Recognized, File No. E187184

TYPICAL APPLICATIONS

- * Converter For UPS , VVVF and Servo Motor Drive Amplifier



Approx Net Weight:200g

Pert of Diode Bridge and Thyristor Maximum Ratings

Parameter		Conditions	Max Rated Value	Unit	
Average Rectified Output Current	$I_{O(AV)}$	3 Phase Full Wave Rectified $T_c=95^\circ\text{C}(\text{Non-Bias})$ $T_c=70^\circ\text{C}(\text{Biased})$	100	A	
Operating JunctionTemperature Range	T_{jw}	$T_j>125^\circ\text{C}$, Can not be Biased for Thyristor	-40 to +150	$^\circ\text{C}$	
Storage Temperature Range	T_{stg}		-40 to +125	$^\circ\text{C}$	
Isoration Voltage	Viso	Base Plate to Terminals, AC1min.	2500	V	
Mounting torque	Case mounting	Ftor	Greased	2.4 to 2.8	N.m
	Terminals		M5 Screw		

Thermal Characteristics

Characteristics	Symbol	Test Conditions	Maximum Value.	Unit
Thermal Resistance	$R_{th(c-f)}$	Case to Fin,Total,Greased	0.06	$^\circ\text{C/W}$

Part of Diode Bridge (6 dies)

Maximum Ratings

Parameter	Symbol	Grade	Unit
		PGH10016AM	
Repetitive Peak Reverse Voltage *1	V_{RRM}	1600	V
Non Repetitive Peak Reverse Voltage *1	V_{RSM}	1700	

Parameter	Symbol	Conditions	Max Rated Value	Unit
Surge Forward Current *1	I_{FSM}	50 Hz Half Sine Wave,1Pulse, Non-Repetitive	1200	A
I Squared t *1	I^2t	2msec to 10msec	7200	A^2s
Allowable Operating Frequency	f		400	Hz

*1 Value Per 1 Arm



Electrical • Thermal Characteristics

Characteristics	Symbol	Test Conditions	Maximum Value.			Unit
Peak Reverse Current *1	I_{RM}	$V_{RM}= V_{RRM}, T_j= 125^{\circ}C$			20	mA
Peak Forward Voltage *1	V_{FM}	$I_{FM}= 100A, T_j=25^{\circ}C$			1.20	V
Thermal Resistance	$R_{th(j-c)}$	Junction to Case (Total)			0.24	$^{\circ}C/W$

*1 Value Per 1 Arm

Part of Thyristor (1 die)

Maximum Ratings

Parameter	Symbol	Grade		Unit
		PGH10016AM		
Repetitive Peak Off-State Voltage	V_{DRM}	1600		V
Non Repetitive Peak Off-State Voltage	V_{DSM}	1700		
Repetitive Peak Reverse Voltage	V_{RRM}	1600		V
Non Repetitive Peak Reverse Voltage	V_{RSM}	1700		

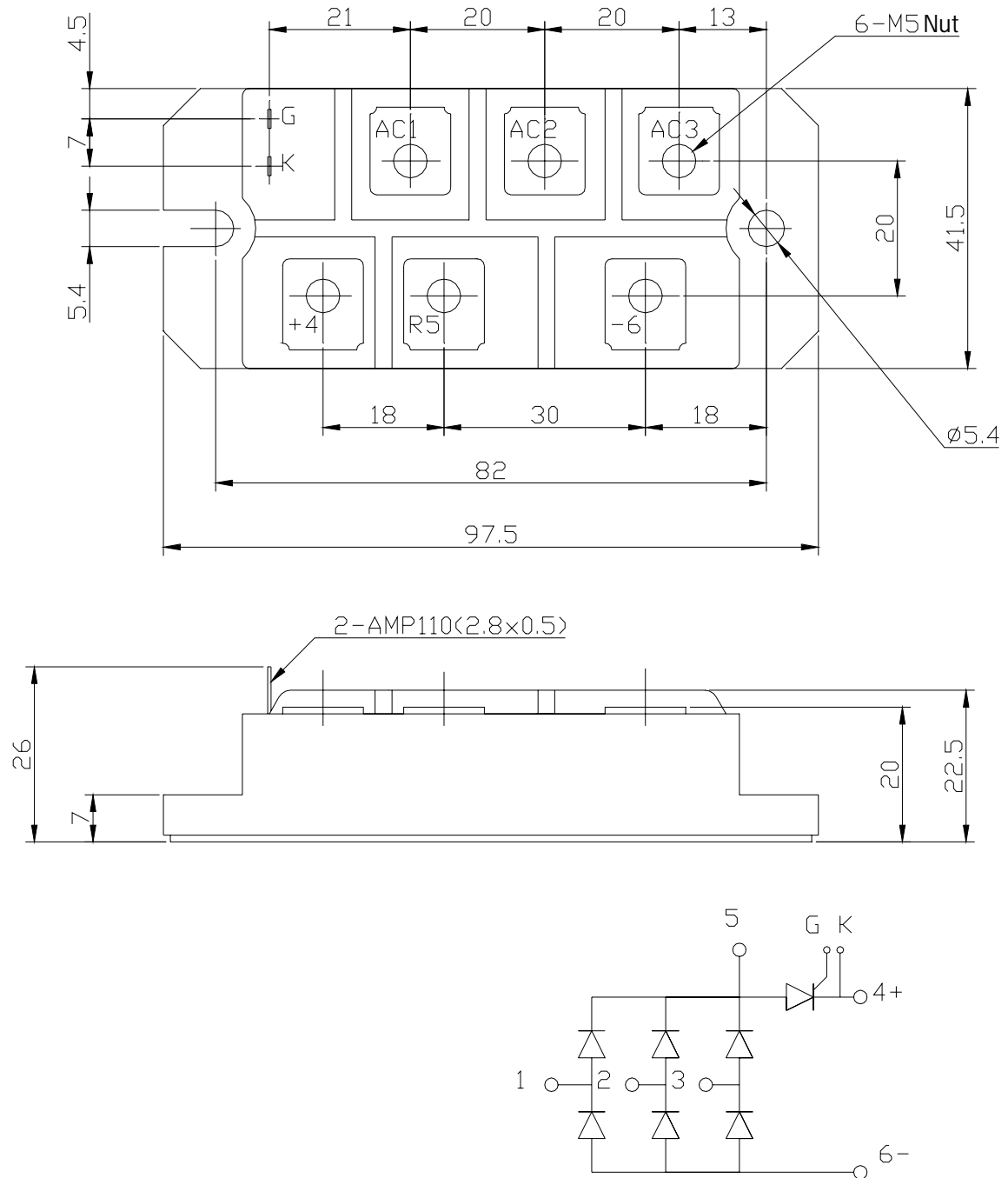
Parameter	Symbol	Conditions	Max Rated Value	Unit
Surge On-State Current	I_{TSM}	50 Hz Half Sine Wave, 1 Pulse Non-Repetitive	2000	A
I Squared t	I^2t	2msec to 10msec	20000	A^2s
Critical Rate of Turned-On Current	di/dt	$V_D=2/3V_{DRM}, I_{TM}=2 \cdot I_O, T_j=125^{\circ}C$ $I_G=200mA, di_G/dt=0.2A/\mu s$	100	$A/\mu s$
Peak Gate Power	P_{GM}		5	W
Average Gate Power	$P_{G(AV)}$		1	W
Peak Gate Current	I_{GM}		2	A
Peak Gate Voltage	V_{GM}		10	V
Peak Gate Reverse Voltage	V_{RGM}		5	V

Electrical • Thermal Characteristics

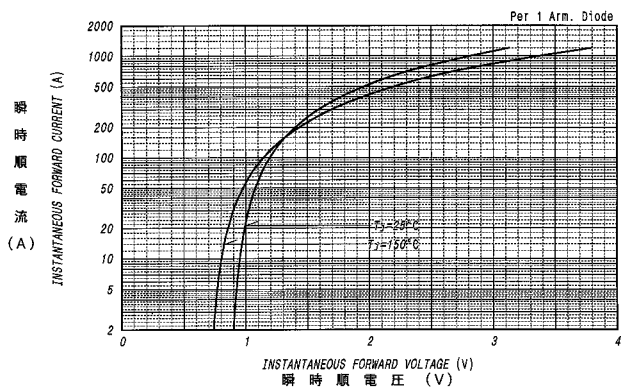
Characteristics	Symbol	Test Conditions	Maximum Value.			Unit
			Min.	Typ.	Max.	
Peak Off-State Current	I_{DM}	$V_{DM}= V_{DRM}, T_j= 125^{\circ}C$			20	mA
Peak Reverse Current	I_{RM}	$V_{RM}= V_{RRM}, T_j= 125^{\circ}C$			20	mA
Peak On-State Voltage	V_{TM}	$I_{TM}= 100A, T_j=25^{\circ}C$			1.10	V
Gate Current to Trigger	I_{GT}	$V_D=6V, I_T=1A$	$T_j=-40^{\circ}C$		200	mA
			$T_j=25^{\circ}C$		100	
			$T_j=125^{\circ}C$		50	
Gate Voltage to Trigger	V_{GT}	$V_D=6V, I_T=1A$	$T_j=-40^{\circ}C$		4	V
			$T_j=25^{\circ}C$		2.5	
			$T_j=125^{\circ}C$		2	
Gate Non-Trigger Voltage	V_{GD}	$V_D=2/3V_{DRM} T_j=125^{\circ}C$	0.25			V
Critical Rate of Rise of Off-State Voltage	dv/dt	$V_D=2/3V_{DRM} T_j=125^{\circ}C$	500			$V/\mu s$
Turn-Off Time	t_q	$I_{TM}=I_O, V_D=2/3V_{DRM}$ $dv/dt=20V/\mu s, V_R=100V$ $-di/dt=20A/\mu s, T_j=125^{\circ}C$		150		μs
Turn-On Time	t_{gt}	$V_D=2/3V_{DRM} T_j=125^{\circ}C$ $I_G=200mA, di_G/dt=0.2A/\mu s$		6		μs
Delay Time	t_d			2		μs
Rise Time	t_r			4		μs
Latching Current	I_L	$T_j=25^{\circ}C$		100		mA
Holding Current	I_H	$T_j=25^{\circ}C$		80		
Thermal Resistance	$R_{th(j-c)}$	Junction to Case			0.5	$^{\circ}C/W$



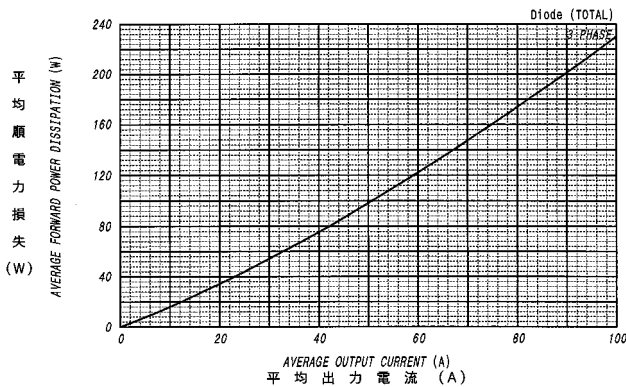
PGH10016AM OUTLINE DRAWING (Dimensions in mm)



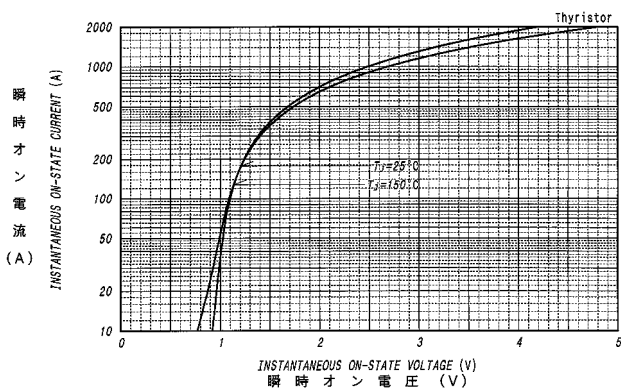
順電圧特性
FORWARD CURRENT VS. VOLTAGE



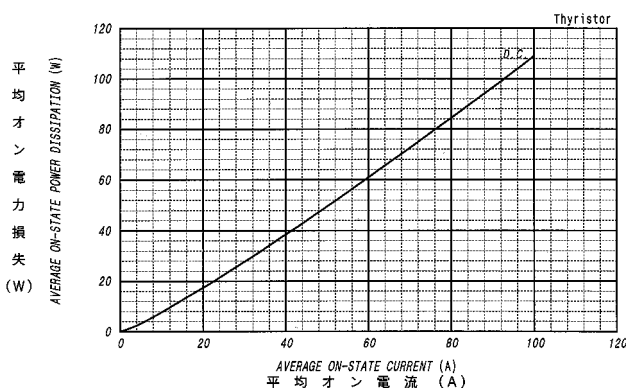
平均順電力損失特性
AVERAGE FORWARD POWER DISSIPATION



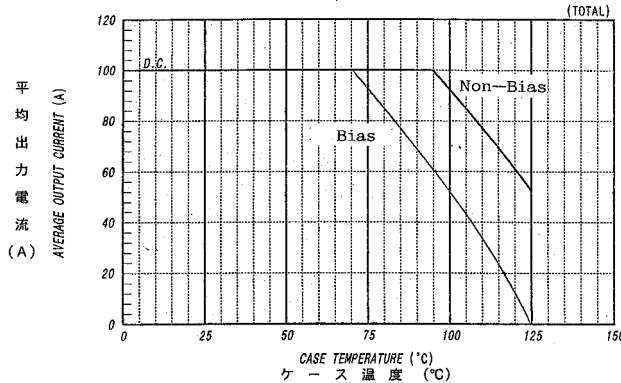
オン電圧特性
ON-STATE CURRENT VS. VOLTAGE



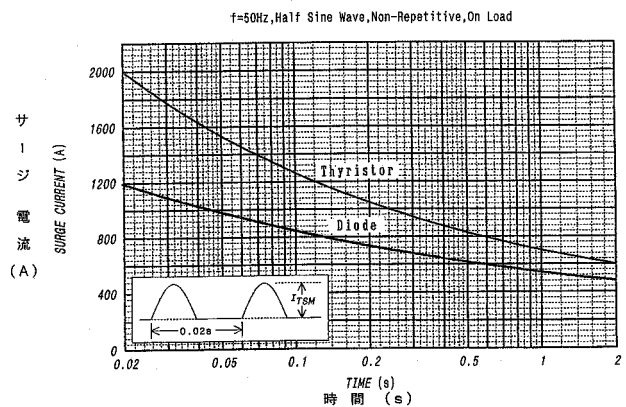
平均オン電力損失特性
AVERAGE ON-STATE POWER DISSIPATION



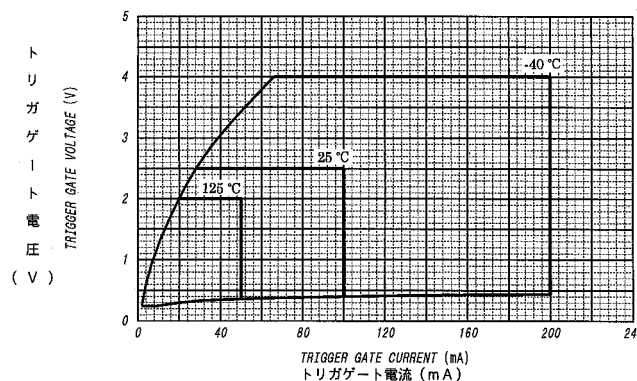
平均出力電流 - ケース温度定格
AVERAGE OUTPUT CURRENT VS. CASE TEMPERATURE
3-Phase Full Wave, Resistive or Inductive Load



サージ電流定格
SURGE CURRENT RATINGS



ゲート特性
GATE CHARACTERISTICS



ゲート定格
GATE RATINGS

